## NSN 5961-00-005-1919

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View Online at https://aerobasegroup.com/nsn/5961-00-005-1919 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches Thread Size: 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage, dc with base short-circuited to emitter and 80.0 collector to emitter voltage/static/base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 10138-50266 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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